DFB/EA Laser Module for 10 Gb/s Applications

Key Features

- 1550 nm DFB CW source monolithicly integrated with an Electro Absorptionmodulator (EA)
- Hermetic, 7 pin butterfly package
- Single-mode fiber pigtail
- 12 GHz typical bandwidth
- -2 dBm output power
- Multisourced footprint

Applications

- SDH STM-64
- SONET OC-192



Description

The laser module, intended for OC-192/STM-64 applications, consists of a DFB laser with integrated absorption modulator mounted in a high frequency package which includes an isolator.



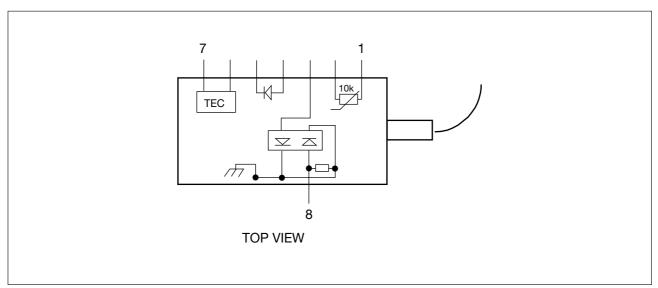


Figure 1. Block diagram

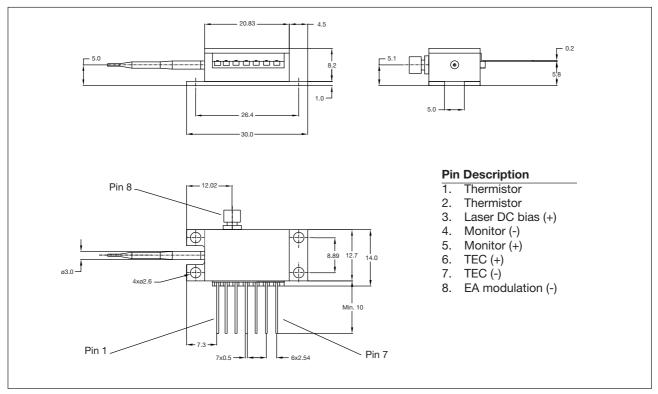


Figure 2. Pin description

Optical Characteristics

Electrical and optical characteristics at recommended operating conditions, unless otherwise noted.

Parameter	Conditions	Symbol	Min	Тур	Max	Unit
Wavelength		λ	1530		1565	nm
Output power	BOL	P _{out}	-2			dBm
Extinction ratio	2.5 V _{pp}	ER	10			dB
Dispersion penalty	@ 50 ps/nm disp.			0	0.5	dB
Side mode suppr.ratio		SMSR	35			dB
Optical isolation			30			dB

Electrical Characteristics

Parameter	Conditions	Symbol	Min	Тур	Max	Unit
Operating current		I _{Op}	50		100	mA
Treshold current		I _{th}			25	mA
Forward coltage		V_{f}			2	V
Reflection, S ₁₁	0 - 5 GHz				-10	dB
	5 – 9 GHz				-8	dB
Small signal modulation bandwidth	-3 dB _e	f _c	12			GHz
Rise/Fall time	10/90%	t _r /t _f			40	ps
Monitor current		I _{Mon}	0.1		1	mA
Monitor dark current	-5 V			5	100	nA
Thermistor resistance	@ 25 °C		9.5		10.5	kΩ
TEC Voltage			-2.5		2.5	V
Current			-1.2		1.2	Α
Power					3	W

Operating Conditions

Parameter	Symbol	Min	Тур	Max	Unit
Operating case temperature	T _{Case}	0		70	°C
Operating chip temperature	T _{Op}	20		30	°C

Absolute Maximum Ratings

3				
Parameter	Symbol	Min	Max	Unit
Storage temperature	T _{Stg}	-40	85	°C
Laser forward current	I _{LD}		150	mA
Modulator voltage	V_{Mod}	-4	1	V

CAUTION: Stresses outside those listed in "Absolute Maximum Ratings" may cause permanent damage to the device.

Handling Precautions

This device may be damaged as a result of electrostatic discharge (ESD). Take proper precautions during both handling and testing. This typically includes grounded wrist wraps, workbenches and floor mats in ESD controlled areas. Semiconductor devices may be damaged by current surges, use appropriate transient protection.

Quality Assurance

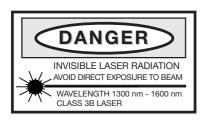
Ericsson Microelectronics commitment to quality has been proven through a decade of semiconductor device production and has been confirmed to ISO 9001. Opto product qualification is made according to the intention of applicable Telcordia standards.

Connector Options

FC/PC

SC

(Other connectors available on request)



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Ericsson Microelectronics AB

SE-164 81 Kista, Sweden Telephone: +46 8 757 50 00 www.ericsson.com/microelectronics

For local sales contacts, please refer to our website or call: Int + 46 8 757 47 00, Fax: +46 8 757 47 76